MOSFETs Silicon N-channel MOS (U-MOSⅧ-H)

TK46A08N1

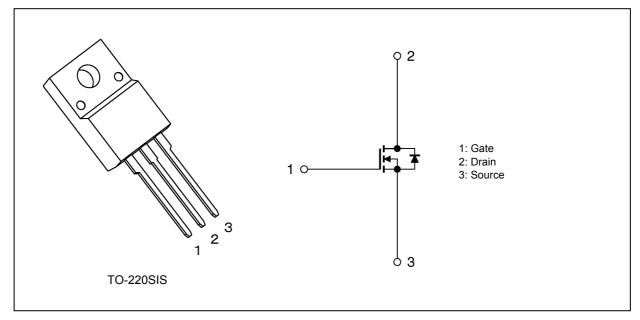
1. Applications

• Switching Voltage Regulators

2. Features

- (1) Low drain-source on-resistance: $R_{DS(ON)} = 6.9 \text{ m}\Omega$ (typ.) ($V_{GS} = 10 \text{ V}$)
- (2) Low leakage current: $I_{\rm DSS}$ = 10 μA (max) (V_{\rm DS} = 80 V)
- (3) Enhancement mode: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_{D} = 0.5 mA)

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristi	cs		Symbol	Rating	Unit
Drain-source voltage			V _{DSS}	80	V
Gate-source voltage			V _{GSS}	±20	
Drain current (DC)	(Silicon limit)	(Note 1), (Note 2)	I _D	80	A
Drain current (DC)	(T _c = 25°C)	(Note 1)	Ι _D	46	
Drain current (pulsed)	(t = 1 ms)	(Note 1)	I _{DP}	169	
Power dissipation	(T _c = 25°C)		PD	35	W
Single-pulse avalanche energy		(Note 3)	E _{AS}	59	mJ
Avalanche current			I _{AR}	46	A
Channel temperature			T _{ch}	150	°C
Storage temperature			T _{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Start of commercial production 2012-05

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R _{th(ch-c)}	3.57	°C/W
Channel-to-ambient thermal resistance	R _{th(ch-a)}	62.5	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: Limited by silicon chip capability.

Note 3: V_DD = 64 V, T_ch = 25°C (initial), L = 21.7 μ H, I_{AR} = 46 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

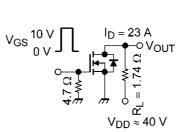
6.1. Static Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V	_	_	±0.1	μA
Drain cut-off current	I _{DSS}	V _{DS} = 80 V, V _{GS} = 0 V	_	—	10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	80		_	V
Drain-source breakdown voltage (Note 4)	V _{(BR)DSX}	I _D = 10 mA, V _{GS} = -20 V	60		_	
Gate threshold voltage	V _{th}	V _{DS} = 10 V, I _D = 0.5 mA	2.0	—	4.0	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 10 V, I _D = 23 A		6.9	8.4	mΩ

Note 4: If a reverse bias is applied between gate and source, this device enters V_{(BR)DSX} mode. Note that the drainsource breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 40 V, V _{GS} = 0 V, f = 1 MHz		2500	—	pF
Reverse transfer capacitance	C _{rss}			22	_	
Output capacitance	C _{oss}		_	620	—	
Gate resistance	r _g	_	_	2.8	—	Ω
Switching time (rise time)	tr	See Figure 6.2.1	_	11	_	ns
Switching time (turn-on time)	t _{on}			30	_	
Switching time (fall time)	t _f			17	_	
Switching time (turn-off time)	t _{off}		_	51		



Duty \leq 1%, t_W = 10 μ s

Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics ($T_a = 25^{\circ}C$ unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD} \approx 64 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 46 \text{ A}$	—	37	_	nC
Gate-source charge 1	Q _{gs1}		_	14	_	
Gate-drain charge	Q _{gd}		_	9.8	_	
Gate switch charge	Q _{SW}		_	16	_	

6.4. Source-Drain Characteristics (Ta = 25°C unless otherwise specified)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (DC)	(Note 5)	I _{DR}	—	_	_	46	A
Reverse drain current (pulsed)	(Note 5)	I _{DRP}	—	_	—	169	
Diode forward voltage		V _{DSF}	I _{DR} = 46 A, V _{GS} = 0 V	_	—	-1.2	V
Reverse recovery time	(Note 6)	t _{rr}	I _{DR} = 46 A, V _{GS} = 0 V		59		ns
Reverse recovery charge	(Note 6)	Q _{rr}	-dI _{DR} /dt = 100 A/µs	_	97	_	nC

Note 5: Ensure that the channel temperature does not exceed 150°C. Note 6: Ensure that V_{DS} peak does not exceed V_{DSS}.

7. Marking (Note)

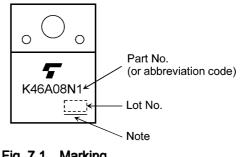


Fig. 7.1 Marking

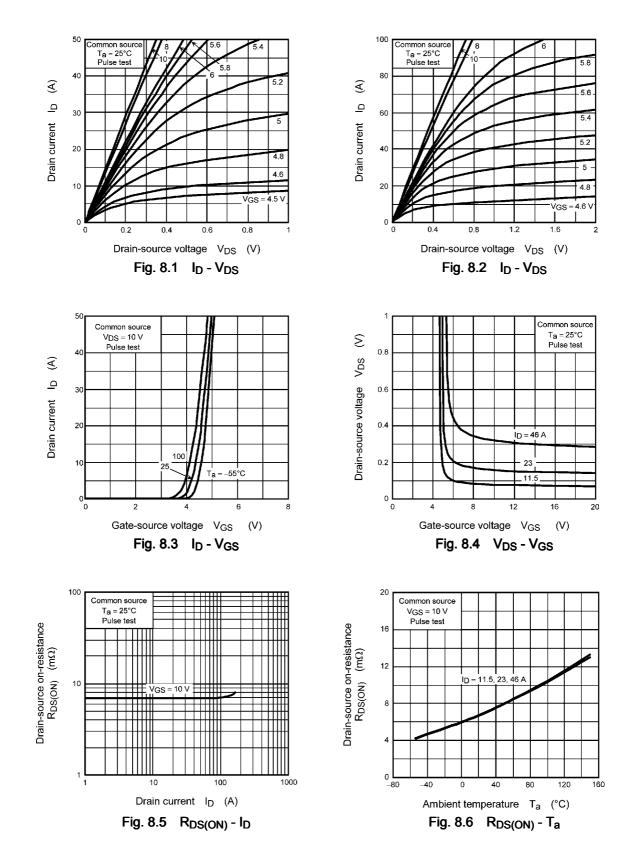
Note: A line under a Lot No. identifies the indication of product Labels. Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

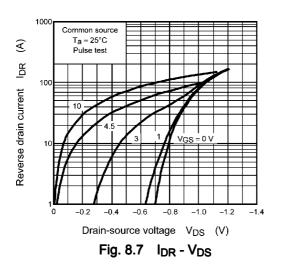
The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

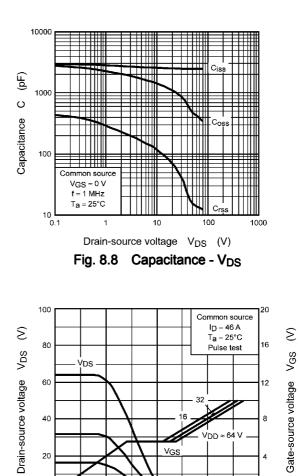
8. Characteristics Curves (Note)

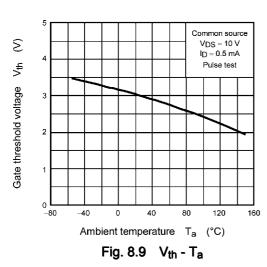


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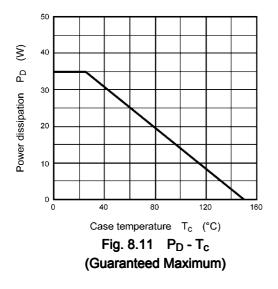
Total gate charge Q_g (nC) Fig. 8.10 Dynamic Input/Output Characteristics

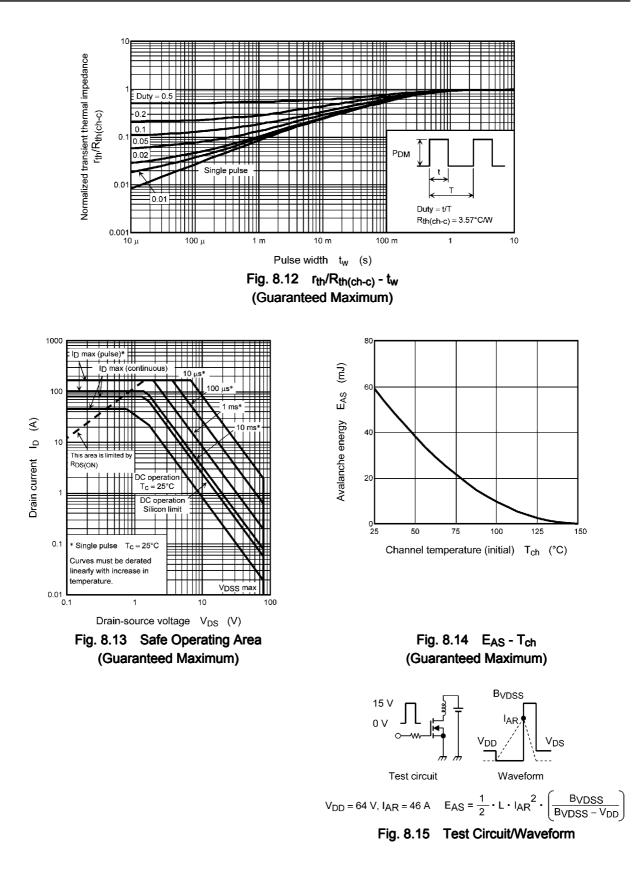
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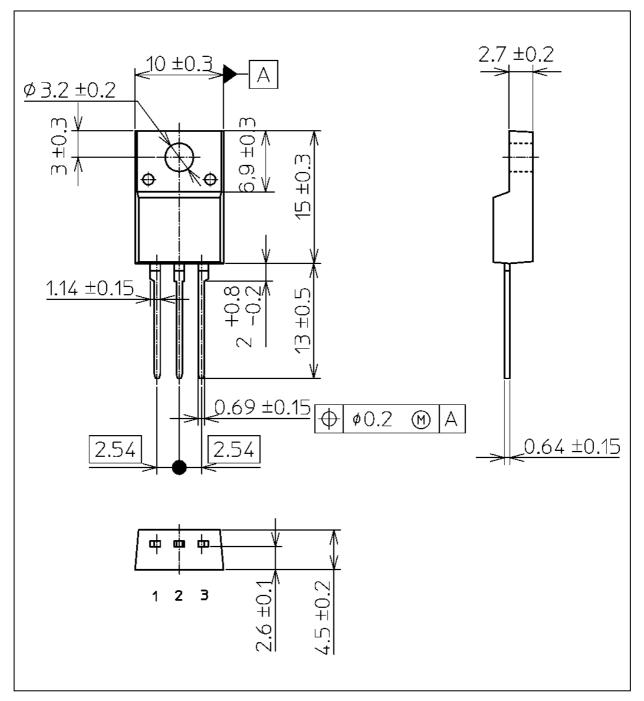


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Package Dimensions

TK46A08N1

Unit: mm



Weight: 1.7 g (typ.)

Package Name(s)	
JEITA: SC-67	
TOSHIBA: 2-10U1S	
Nickname: TO-220SIS	

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